

SOFT X-RAY PHOTOELECTRON SPECTROSCOPY AND ITS APPLICATIONS

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Ecole Polytechnique Fédérale de Lausanne Swiss Light Source, Paul Scherrer Institut

- Introduction to photoelectron spectroscopy
- Case studies on BiTeCI and topological insulator
- Spin- and angle-resolved photoemission spectroscopy
- Manipulating spin texture of 2DEG on SrTiO₃

E.B. Guedes et al. Physical Review Research 2, 033173 (2020)

• Operando (S)ARPES on multiferroic (Ge,Mn)Te

J. Krempasky et al. Physical Review X 8, 021067 (2018)

• Measuring time without a clock M. Fanciulli et al. Physical Review Letters 118, 067402 (2017)



Photoelectric effect

Einstein's Photoelectric Equation

The electron leaves the body with energy

 $\frac{1}{2}mv^2 = hv - P,$

where *h* is Planck's constant, *v* is the light frequency and P is the work the electron has to do in leaving the body.



Albert Einstein, 1905

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In his 1913 letter nominating Einstein for the membership of Prussian Academy, Max Planck wrote:

"In sum, one can say there is hardly one among the great problems in which modern physics is so rich to which Einstein has not made a remarkable contribution. That he may sometimes have missed the target in his speculations, as, for example, in his hypothesis of light quanta, cannot really be held too much against him, for it is not possible to introduce really new ideas even in the most exact sciences without sometimes taking a risk."





X-ray photoelectron spectroscopy (XPS)

PHYSICAL REVIEW

VOLUME 105. NUMBER 5

Precision Method for Obtaining Absolute Values of Atomic Binding Energies

CARL NORDLING, EVELYN SOKOLOWSKI, AND KAI SIEGBAHN

Department of Physics, University of Uppsala, Uppsala, Sweden

(Received January 10, 1957)

W^E have recently developed a precision method of investigating atomic binding energies, which we investigating atomic binding energies, which we believe will find application in a variety of problems in atomic and solid state physics. In principle, the method is an old one: a magnetic analysis of electrons expelled from a substance exposed to x-radiation. Previous attempts in this direction have, however, given considerably less information about atomic structure than ordinary x-ray spectroscopic experiments, and some twenty years ago the method seems to have been definitely abandoned. We have introduced a number of improvements, both regarding the intensity and, in particular, the accuracy (a factor 100), which now enables us to measure atomic binding energies with an accuracy of one single electron volt from microgram quantities. The definition of the lines is essentially limited by the natural line widths of the atomic levels themselves. There is no shift of the lines due to electron scattering or similar causes. which could introduce systematic errors.



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49

652

641

84

769

25 Mn



Quantitative aspects: Atomic cross section



Quantitative aspects: Dependency on emission angle

Distance travelled in material increases rapidly with angle Electron mean free path ~2 nm Determine chemical composition of top few atomic layers (surface termination)



Photon penetration depth not relevant here





Bi₂Tel What termination?

Quantitative aspects: Dependency on emission angle

Distance travelled in material increases rapidly with angle Electron mean free path ~2 nm Determine chemical composition of top few atomic layers (surface termination)

Photon penetration depth not relevant here

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Bi₂Tel What termination?

X-ray photoelectron diffraction (XPD)

Combine XPS and fine angular resolution

S.D. Ruebush et al. Surface Science 421, 205 (1999)

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Matsui, Nara Institute of Science and Technology

Scattering of photoemitted electron on local environment Structural determination of surfaces, overlayers, and adsorbates Chemical and sub-monolayer sensitivity Recent developments in holography and dichroic imaging

Review: D.P. Woodruff Surface Science Reports 62, 1 (2007) Recent developments: M.V. Kuznetsov et al. J. Phys. Soc. Jpn. 87, 061005 (2018)

Angle-resolved photoemission spectroscopy (ARPES)

 $E_b = h\nu - \Phi - E_k$

Measurement:

- Kinetic energy \rightarrow Binding energy
- **Emission angle** \rightarrow momentum k $k_{||} = 0.512\sqrt{E_k} \sin \theta$ 2)
- Asymmetry \rightarrow Spin polarization vector 3)

Change photon energy to acces 3D momentum

"See how the electrons move in the crystal"

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"See how the electrons move in the crystal"

Quantitative aspect: Matrix element effects

Relies on **sudden approximation**: photoelectron emitted from N particle system does not interact with N-1 system *after* photo-excitation

<u>Fermi's Golden Rule for transition probability:</u>

$$w = \frac{2\pi}{\hbar} |\langle \Psi_f | H_{int} | \Psi_i \rangle|^2 \delta(E_f - E_i - \hbar\omega)$$

For accessible extensive description:

S. Moser J. Electron Spectroscopy and Related Phenomena 214, 29 (2017)

photon polarization in...

...perpendicular ("senkrecht") to...scattering plane

Plane wave always even	Even for p-pol odd for s-pol		Depends on band symmetry (s, p _{x,y,z})	
	$\left \Psi_{f} \right\rangle$	A ullet p	$ \psi$	$_{i}$
p - pol.	+1	+1	-1	0
	+1	+1	+1	max.
s - pol.	+1	-1	-1	max.
	+1	-1	+1	0

BiteCl as example

No inversion symmetry and morphic HYSIKALISCHE GESERS to detrmine surface termination sikalischer RRES to see shift in bands and match to DETO

hv=80 eV b) — Cl term. a) — Te term. 4d_{5/2} CI 0.0 0.0 240 meV 15 0.5 0.5 Bi 5d_{5/2} (eV) energy (eV) $4d_{3/2}$ counts (10³) energy 1.0 1.0 Те 10 binding binding 1.5 .5 $5d_{3/2}$ 5 -2.0 2.0 ш 2.5 2.5 -0.4 -0.2 0.0 0.2 0.4 -0.4 -0.2 0.0 0.2 0.4 36 40 28 44 24 $k_{\Gamma-K}$ (Å⁻¹) $k_{\Gamma-K}$ (Å⁻¹) binding energy (eV) hv dependence to usunguish surrace and burk states (re-termination) $\Gamma^9 A^9 \Gamma^{10}$ A^9 b) Photon induced chemistry 0.0 destroys surface states on € 0.5 · **CI-termination** ergy Band visible bindir 1.5 only in every 2.0 – 2nd BZ due to 2.5 – interference 4.0 4.4 4.8 5.2 5.6 -0.4 -0.2 0.0 0.2 0.4 -0.4 -0.2 0.0 0.2 0.4 -0.4 -0.2 0.0 0.2 0.4

 $k_{\Gamma-K}$ (Å⁻¹)

 $k_{\Gamma-K}$ (Å⁻¹)

 $k_{\Gamma-A} (\text{\AA}^{-1})$

Some remarks on soft X-ray ARPES (SX-ARPES)

- Larger mean free path increases probing depth (main signal still from surface region)
- Increased damping distance enhances k_z resolution ($\Delta k_z = \lambda^{-1}$): large problem at low hv
- High kinetic energies mean final state feels less of crystal potential: more free electron-like
- \rightarrow Simplified matrix element and "cleaner" spectrum

Price to pay: less good resolution (40meV vs. 4meV) and lower count rate

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<u>QC: quantum confinement</u> Shockley surface states Quantum well states

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Soft X-ray ARPES on sputtered topological insulator Bi₂Se₃

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Topological protection: At interface of change in topology in-gap state **must** exist Protection occurs by state moving away from areas with high defects Probed with relatively high hv

intensity (a.u.)

 $\top 0$

R. Queiroz et al. PRB 93, 165409 (2016)

Soft X-ray ARPES on sputtered topological insulator Bi₂Se₃

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Gaussian disorder by surface adsorbates reduces overall intensity

Unitary disorder by sputtering reduces influence of Gaussian disorder

13

intensity (a.u.)

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R. Queiroz et al. PRB 93, 165409 (2016)

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Localised surface states

PRL 109, 116403 (2012)

Disentanglement of Surface and Bulk Rashba Spin Splittings in Noncentrosymmetric BiTeI

SOIS: Spin-Orbit Interaction Spectroscopy group

1. **Spin-orbitronics**: Rashba effect, Spintronics "without" magnetism

3. Extra tag in spectroscopy: photoelectron time scale, orbital mapping, phase determination, quasiparticle interactions ...

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part of Laboratory for Topological Matter www.epfl.ch/labs/ltm/

Spin-orbit density wave (SODW) in Pb/Si(557)

C. Tegenkamp et al. PRL 109, 266401 (2012); C. Brand et al. Nature Comm. 6, 8118 (2015)

COPHEE at the Swiss Light Source

Two orthogonal classical (40 kV) Mott detectors Access to "all" quantum numbers of the electron: energy, momentum (3D) and spin (3D)

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For reviews on SARPES on SOI systems see: J.H. Dil, J. Phys.: Cond. Matt. 21, 403001 (2009) and U. Heinzmann and J.H. Dil, J. Phys.: Cond. Matt. 24, 173001 (2012)

For review of SARPES on Topological Materials see: J.H. Dil, Elec. Structure 1 023001 (2019)

Next generation: iMott

New version under commissioning now Full spin-resolved 2D (E_k , θ) band structure in one shot Enhancement of efficiency by ~10⁴

Single event detection also very suitable for low intensity (spin integrated) spectroscopy

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V. Strocov, V. Petrov, and J.H. Dil, J. Synchrotron Radiation 22, 708 (2015)

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For other approaches see:

G. Schönhense et al. J. Electron Spectrosc. Relat. Phenom. 200, 94 (2015) T. Okuda J. Phys.: Condens. Matter 29 483001 (2017)

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Sources of spin polarization in SARPES

"All" photoelectrons are highly spin polarised

Spin polarized initial states:

- Magnetic systems
- Spin-orbit interaction (Rashba, topological materials)

Photoemission induced effects:

- Change of initial state spin: spin interference, geometry induced effects, ...
- Spin induced in spin-degenerate initial state: geometry effects, dipole selection rules, interference of transitions, ...

Basis vectors of spin space

In coherent summation spin rotate

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$$\varphi_{x+} = \frac{1}{\sqrt{2}} \begin{pmatrix} 1\\1 \end{pmatrix}, \quad \varphi_{x-} = \frac{1}{\sqrt{2}} \begin{pmatrix} 1\\-1 \end{pmatrix}$$
$$\varphi_{y+} = \frac{1}{\sqrt{2}} \begin{pmatrix} 1\\i \end{pmatrix}, \quad \varphi_{y-} = \frac{1}{\sqrt{2}} \begin{pmatrix} 1\\-i \end{pmatrix}$$
es
$$\varphi_{z+} = \begin{pmatrix} 1\\0 \end{pmatrix}, \quad \varphi_{z-} = \begin{pmatrix} 0\\1 \end{pmatrix}$$

SmB₆ a topological "Kondo" insulator

N. Xu et al. Nature Communications 5, 4566 (2014).

Band gap (40 meV) by definition always around Fermi level due to mixed valence Spin polarised topological surface states in band gap No sign of correlations in the spin structure Independent verification for (111) surface: Y. Ohtsubo et al. Nature Comm. 10, 2298 (2019)

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Rashba type spin-orbit interaction

Size of splitting depends on: -atomic number -orbital overlap -potential gradient at surface

- Original model based on Lorentz transformation
- Six orders of magnitude wrong
- Rashba terminology maintained for historical and symmetry reasons (Rashba-type)

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Origin in local wave function distribution 0.2 Å around heavy atom core:

$$\Delta E_i \propto k_{\parallel} \int_{\Delta z} \mathrm{d}z \frac{\partial V}{\partial z} |\psi(z)|^2$$

Total measured Rashba splitting is sum of all contributions

G. Bihlmayer et al. Surf. Sci. 600, 3888 (2006) M. Nagano et al. J. Phys.: Condens. Matter 21, 064239 (2009).

Relevance of the Rashba effect

by small voltage pulse V Magnetic layer NiFe Rashba system Ag B: $\checkmark \rightarrow$ To be used, spurious effects from substrate or bulk have to be negligible and the system tunable V: Α s-wave superconductor Majorana ferm

opular e 539

SOIS: Spin-Orbit Interaction Spectroscopy group

- G. Landolt et al. PRL 109, 116403 (2012) C. Tegenkamp et al. PRL 109, 266401 (2012) B. Slomski et al. Scientific Reports 3, 1963 (2013) G. Landolt et al. NJP 15, 085022 (2013) B. Slomski et al. NJP 15, 125031 (2013) A. Santander-Syro et al Nature Mat. 13, 1085 (2014) G. Landolt et al. PRB 91, 081201(R) (2015) J. H. Dil et al. JESRP 201, 42 (2015) C. Brand et al. Nature Comm. 6, 8118 (2015) J. Krempasky et al. Nature Comm. 7, 13071 (2016)

2. Novel topological phases: Topological insulators; Topological protection and transition, type-I and -II Weyl semimetals

D. Hsieh et al. Science 323, 919 (2009) J.W. Wells et al. PRL 102, 096802 (2009) D. Hsieh et al. Nature 460, 1101 (2009) D. Hsieh et al. PRL 103, 146401 (2009) D. Hsieh et al NJP 12, 125001 (2010) S.Y. Xu et al. Science 332, 560 (2011) S.V. Eremeev et al. Nature Comm. 3:635 (2012)

F. Meier et al. PRB 77, 165431 (2008)

H. Dil et al. PRL 101, 266802 (2008)

F. Meier et al. NJP 11, 125008 (2009)

J. Lobo et al. PRL 104, 187602 (2010)

I. Gierz et al. PRB 81, 245430 (2010)

I. Gierz et al PRB 83, 195122 (2011)

P. King et al. PRL 107, 096802 (2011)

B. Slomski et al. B 84, 193406(B) (2011)

P. Höpfner et al. PRL 108, 186801 (2012)

F. Meier et al. PRB 79, 241408(R) (2009)

- S. Muff et al. PRB 88, 035407 (2013)

F. Meier et al. JPCM 23, 072207 (2011) C. Veenstra et al PRL 112, 127002 (2014) M. Fanciulli et al PRL 118, 067402 (2017) E. Razzoli et al. PRL 118, 086402 (2017)

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Influence of spin-orbit interaction (SOI) in solid state physics

1. Spin-orbitronics: Rashba effect; model systems, transition metal oxides, ferroelectrics, multiferroics

J. Krempasky et al. PRB 94, 205111 (2016) S. Muff et al. App. Surf. Sci. 432, 41 (2018) J. Krempasky et al. PRX 8, 021067 (2018) S. Muff et al. PRB 98, 045132 (2018) M. Jäger et al. PRB 98, 165422 (2018) M. Jäger et al. Phys. Status Solidi B, 1900152 (2019) D. Krieger et al. Crystals 9, 335 (2019) J. Krempasky et al. PRR 2, 013107 (2020) G. Kremer et al. PRR 2, 033115 (2020) E.B. Guedes et al. PRR 2, 033173 (2020)

S.Y. Xu et al. Nature Physics 8 616 (2012) S.Y. Xu et al. Nature Comm. 3, 1192 (2012) N. Xu et al. PRB 88, 121102(R) (2013) A. Barfuss et al. PRL 111, 157205 (2013) G. Landolt et al. PRL 112, 057601 (2014) N. Xu et al. Nature Comm. 5, 4566 (2014)

- F. Pielmeier et al. NJP 17, 023067 (2015) S.Y. Xu et al. Nature Comm. 6, 6870 (2015) B.Q. Lv et al. PRL 115, 217601 (2015) R. Queiroz et al. PRB 93, 165409 (2016) P. Rüssmann et al. PRB 97, 075106 (2018) N. Xu et al. PRL 121, 136401 (2018) A. Weber et al. PRL 121, 156401 (2018)
- J. Hu et al. PRB 100, 115201 (2019)

3. Extra tag in spectroscopy: photoemission time, orbital mapping, phase determination, spin interference

M. Fanciulli et al. PRB 95, 245125 (2017) M. Fanciulli, and J.H. Dil, SciPost Physics 5, 058 (2018).

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F. Meier et al. JPCM 23, 072207 C. Veenstra et al PRL 112, 12700

Mauro Fanciulli M. Fanciulli et al PRL 118, 067 E. Razzoli et al. PRL 118, 0864

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F. Pielmeier et al. NJP 17, 023067 (2015) Marco Caputo 6870 (2015) 5) oz et al. PRB 93, 165409 (2**016)** nann et al. PRB 97, 075106 (2018) al. PRL 121. 136401 (2018) al. PRL 121, 156401 (2018) J. Hu et al. PRB 100, 115201 (2019)

M. Fanciulli et al. PRB 95, 245125 (2017) M. Fanciulli, and J.H. Dil, SciPost Physics 5, 058 (2018).

Many others...

Unsolicited advise: don't aim for best machine, but be versatile and flexible, especially in sample preparation and environment